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KERALA AGRICULTURAL UNIVERSITY B.Tech.(Food Engg) 2018 Admission **II Semester Final Examination- June 2019**

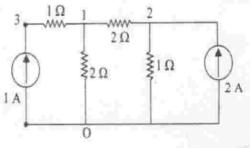
BASIC ELECTRICAL ENGINEERING (2+1)

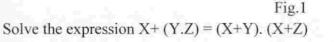
| | | Marks: 50 |
|----|---|----------------------------|
| Ā | Fill up the blanks | Time: 2 hours (10x1=10) |
| 1 | Energy stored by a coil is doubled when its current is increased by | percent |
| 2 | In a series RC circuit as frequency increases current | portai |
| 3 | The r.m.s. value of sinusoidal 100 V peak to peak is volt | |
| 4 | Resistance of a wire is r ohms. The wire is stretched to double resistance in ohms is | its length, then its |
| 5 | A star circuit has each element of resistance R/2. The equivalent delta | elements will be |
| 6 | The power factor of a purely resistive circuit is | |
| В | Answer the following. | |
| 7 | Define dynamically induced emf. | |
| 8 | Define form factor of an alternating quantity. | |
| 9 | Y= BC+AC. Draw the logic gate for this expression | |
| 10 | Draw the V-I characteristics of ideal diode. | |
| | Write Short notes on any FIVE of the following | (5x2=10) |
| 1 | Derive the ripple factor of a full- wave rectifier. | |
| 2 | Kirchhoff's current law. | |
| 3 | Active and passive element with an example. | |
| 4 | An NPN transistor has collector current 4mA and base current 10 μ A. Calculate α and β | |
| | values of the transistor, neglecting the reverse sat current I_{CBO} | |
| | | |

- Convert the Boolean expression in logic gate $F = X + \overline{Y + Z} + X \cdot Y$ 5
- Mutual inductance. 6
- Define Demorgan's theorems. 7

ш Answer any FIVE of the following.

- A three phase load consists of three similar inductive coils, each of resistance 50Ω and 1 inductance 0.3 H. The supply is 415 V, 50Hz. Calculate (a) line current (b) power factor when the load is connected in star.
- Find the voltage across 1 and 2 using nodal analysis of the circuitas shown in Fig.1 2

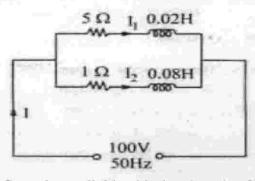




(5x4=20)

- 3
- 4
- 5

4 Find the net impedance and total current in the parallel circuit shown below.



- 5 An NPN transistor used for voltage divider biasing has the following parameters α = 0.985, V_{BE} = 0.3V, Vcc = 16V. If the operating point Q is at I_C= 2mA, V_{CE} = 6V, then calculate R₁ & R_C for R₂= 20kΩ.
- 6 CB operation of transistor.

IV

7 Difference between p type and n type semiconductors.

Answer any ONE of the following

(1x10=10)

- 1 With a neat sketch, explain the working principle of half-wave rectifier and derive the expression for efficiency & output voltage
- 2 State and explain Thevenin's theorem with circuit diagram.
